

# SANYO Semiconductors DATA SHEET

# Thick-Film Hybrid IC STK672-210-E — Unipolar Constant-Current Chopper **Two-Phase Stepping Motor Driver Output Current 1.4A**

#### Overview

The STK672-210-E is two-phase stepping motor driver hybrid IC (HIC) that features further miniaturization and improved input logic flexibility as compared to the STK6712 series products.

### **Applications**

• The STK672-210-E is optimal for use as a stepping motor driver in printers, copiers, XY plotters, and similar equipment.

### **Features**

- Built-in common-mode input protection circuit.
- The input signal logic lines are provided as active-high and active-low pairs, and thus support switching the motor wiring.
- Built-in current detection resistor for reduced external component mounting area on the printed circuit board.
- Wide motor operating range (10 to 45V)

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# **Specifications**

# Absolute Maximum Ratings at $Tc = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage 1	V <sub>CC</sub> 1 max	No signal	52	V
Maximum supply voltage 2	V <sub>CC</sub> 2 max	No signal	-0.3 to +7.0	V
Input voltage	V <sub>IN</sub> max	Logic input pins	-0.3 to +7.0	V
Output current	I <sub>OH</sub> max	0.5s, 1 pulse, when V <sub>CC</sub> 1 is applied	2.2	Α
Allowable power dissipation	Pd max	With an arbitrarily large heat sink. Per MOSFET	6.5	W
Operating substrate temperature	Tc max		105	°C
Junction temperature	Tj max		150	°C
Storage temperature	Tstg		-40 to +125	°C

### Allowable Operating Ranges at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage 1	V <sub>CC</sub> 1	With signals applied	10 to 45	<b>V</b>
Supply voltage 2	V <sub>CC</sub> 2	With signals applied	5.0 ± 5%	V
Input voltage	VIH		0 to V <sub>CC</sub> 2	V
Phase driver withstand voltage	V <sub>DSS</sub>	I <sub>D</sub> = 1mA (Tc = 25°C)	100	٧
Output current 1	I <sub>OH</sub> 1	When the pin 6 to 9 signals are ≥ 100Hz, Tc = 105°C, 50% duty	1.4	А
Output current 2	I <sub>OH</sub> 2	When the pin 6 to 9 signals are ≥ 100Hz, Tc = 90°C, 50% duty	1.6	А

# **Electrical Characteristics** at $Tc = 25^{\circ}C$ , $V_{CC}1 = 24V$ , $V_{CC}2 = 5V$

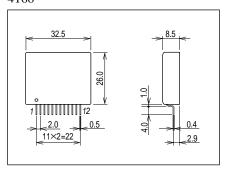
Parameters	0 1 1	Symbols Conditions	Rating			
	Symbols		min	typ	max	unit
Control supply current	lcco	With all inputs at the V <sub>CC</sub> 2 level		3.3	10	mA
Output average current	loave	With R/L = $3.5\Omega/3.8$ mH in each phase	0.405	0.450	0.505	Α
FET diode forward voltage	Vdf	If = 1.0A		1.1	1.8	٧
Output saturation voltage	Vsat	$R_L = 24\Omega$		0.8	1.2	٧
Vref input voltage	VrH	Pin 12	0		3.5	٧
Vref input bias current	I <sub>IB</sub>	With pin 12 at 1V		50	500	nA
[Control Input Pins]						
Input voltage	VIH	HIC pins 6 to 9	3.5			٧
	V <sub>IL</sub>	HIC pins 6 to 9			0.7	٧
Input current	I <sub>IH</sub>	HIC pins 6 to 9, V <sub>IN</sub> = V <sub>CC</sub> 2		310		μΑ
	IIL	HIC pins 6 to 9, V <sub>IN</sub> = 0V		2.5		μА

Note: A fixed-voltage power supply must be used.

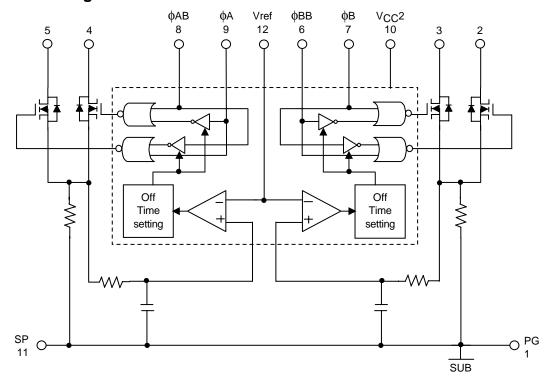
# **Package Dimensions**

unit:mm (typ)

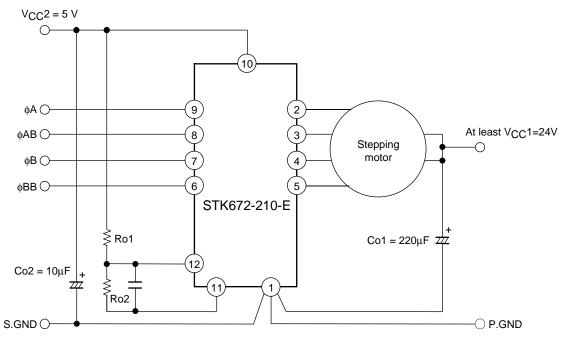
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# **Internal Block Diagram**



# **Sample Application Circuit**

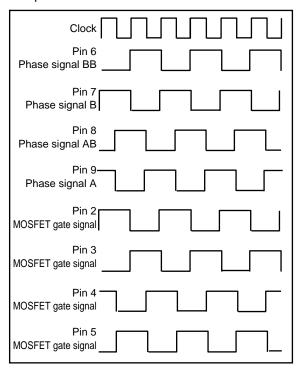


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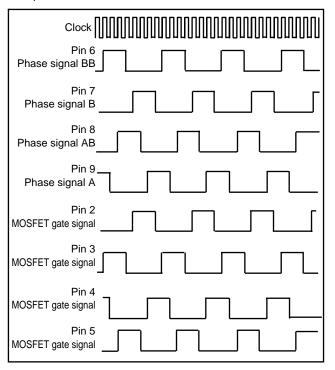
- The Co1 ground lead must be connected as close as possible to pin 1 on the hybrid IC.
- HC type CMOS levels are recommended as the input specifications for pins 6 to 9.
- In case of TTL input, connect a pull-up resistor. (Recommended value:  $2k\Omega$ )
- Excitation control input specifications

1 1			
Corresponding output pin	Corresponding excitation control input signal		
	Active: High	Active: Low	
2 pin	φВ	φВВ	
3 pin	φВВ	φВ	
4 pin	φА	φАВ	
5 pin	φΑВ	φА	

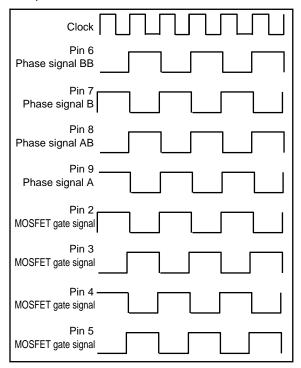
# Phase signal: Active low input 2-phase excitation



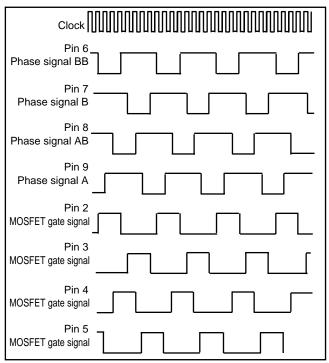
### 1-2 phase excitation



# Phase signal: Active high input 2-phase excitation



## 1-2 phase excitation



# **Setting the Motor Current Peak Value (IOH)**

 $IOH \approx Vref \div Rs$ 

Vref: STK672-210-E pin 12 input voltage

Rs: STK672-210-E internal current detection resistor (0.195 $\Omega$  ±2%)



Model of the Motor Current Flowing into the Driver IC (pins 2, 3, 4, and 5)

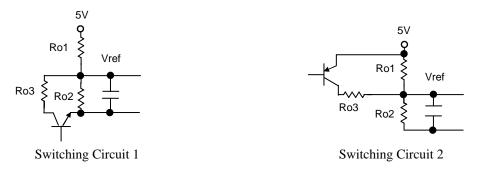
$$Vref = (Ro2 \div (Ro1 + Ro2)) \times V_{CC}2$$
  
 $V_{CC}2 = 5V$ 

### **Current Switching Techniques**

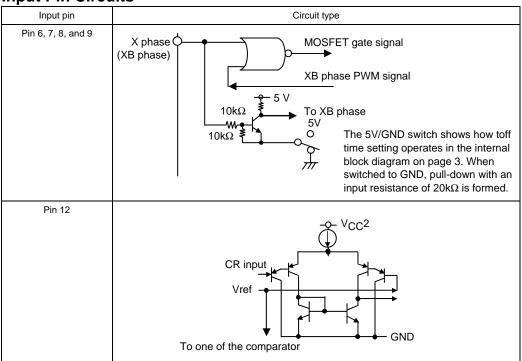
Due to the input bias current (IIB) specifications, Ro1 must be under  $100k\Omega$ .

The figures below present sample circuits that temporarily switch the motor current when, for example a held motor stops.

We recommend using the circuit structure in the figure at the left to minimize as much as possible the effects of the saturation voltage of the reference voltage switching transistor.



### **Input Pin Circuits**



### **Thermal Design**

The size of the heat sink required for the STK672-210-E depends on the output current I<sub>OH</sub> (A), the electrical characteristics of the motor, the excitation mode, and the basic drive frequency.

The thermal resistance (θc-a) of the required heat sink can be determined from the following formula.

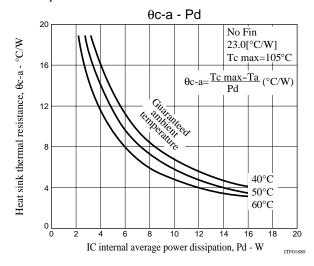
$$\theta c - a = \frac{Tc \max - Ta}{Pd} (°C/W)$$

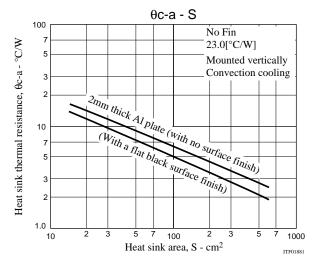
Tc max: The STK672-210-E substrate temperature (°C)

Ta: The STK672-210-E ambient temperature (°C)

Pd: The average internal power dissipation in the STK672-210-E (W)

For example, the required area for a heat sink made from 2mm thick aluminum can be determined from the graph at the right below. Note that the ambient temperature is greatly influenced by the ventilation and air flow patterns within the application. This means that the size of the heat sink must be determined with care so that the STK672-210-E back surface (aluminum substrate) temperature Tc in the mounted state never exceeds, under any conditions that might occur, the temperature  $Tc = 105^{\circ}C$ .





### STK672-210-E Average Internal Power Dissipation Pd

Of the devices that contribute to the STK672-210-E average internal power supply, the devices with the largest power dissipation are the current control devices, the diodes that handle the regenerative current, the current detection resistor, and the predriver circuit.

The following presents formulas for calculating the power dissipation for the different excitation (drive) modes.

2 phase excitation mode

$$Pd_{2EX} = (Vsat + Vdf) \times 0.5 \times CLOCK \times I_{OH} \times t2 + 0.5 \times CLOCK \times I_{OH} \times (Vsat \times t1 + Vdf \times t3) \\ 1-2 \text{ phase excitation mode}$$

 $Pd_{1\text{-}2EX} = (Vsat + Vdf) \times 0.25 \times CLOCK \times I_{OH} \times t2 + 0.25 \times CLOCK \times I_{OH} \times (Vsat \times t1 + Vdf \times t3)$  Motor hold mode

 $Pd_{HOLDEX} = (Vsat + Vdf) \times I_{OH}$ 

Vsat: Ron voltage drop + shunt resistor combined voltage

Vdf: FET internal diode + shunt resistor combined voltage

CLOCK: Input clock (shows clock in the timing charts on page 4)

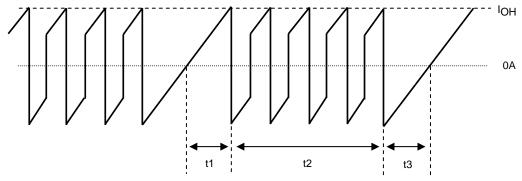


Figure 1 Motor COM current waveform model

### STK672-210-E

t1: The time until the winding current reaches its rated current (IOH)

t2: The time in the constant-current control (PWM) region

t3: The time from the point a phase signal is cut until the back EMF current is dissipated.

 $\begin{aligned} t1 &= (-L/(R+0.77)) \text{ In } (1-((R+0.77)/V_{CC}1) \times I_{OH}) \\ t3 &= (-L/R) \text{ In } ((V_{CC}1+0.77) \, / \, (I_{OH} \times \, R + V_{CC}1 + 0.77)) \end{aligned}$ 

V<sub>CC</sub>1: Motor supply voltage (V)

L: Motor inductance (H)

R: Motor winding resistance ( $\Omega$ )

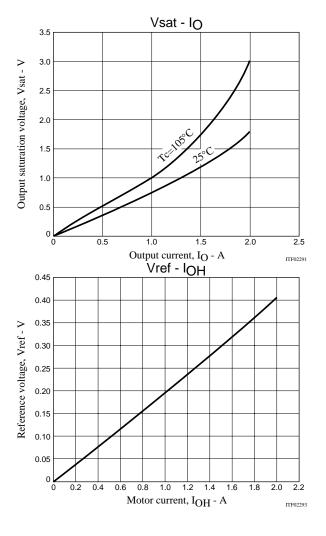
IOH: Set motor output current wave height (A)

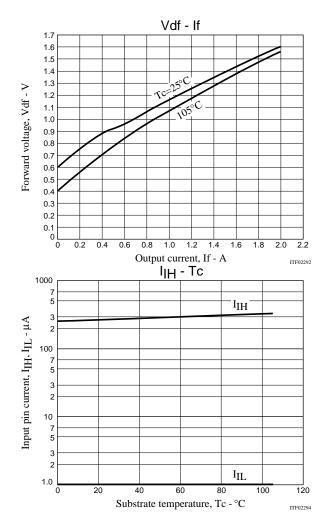
The constant-current control time t2, and the time T = t1 + t2 + t3 that the phase signal is on in each excitation mode are as follows.

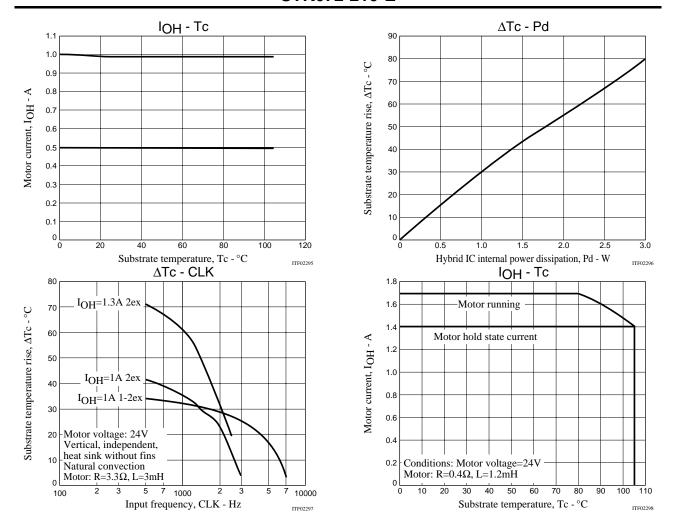
2 phase excitation mode: t2 = (2/Clock) - (t1 + t3)1-2 phase excitation mode: t2 = (3/Clock) - t1

Determine the values for Vsat and Vdf by substitution using the graphs for Vsat vs  $I_{OH}$  and Vdf vs  $I_{OH}$  for the set current value for  $I_{OH}$ . Then judge whether or not a heat sink is required from the determined average power dissipation for the STK672-210-E by comparison with the  $\Delta T_{C}$  vs. Pd graph.

Note that it is necessary to check the temperature rise in the actual application system case, since the STK672-210-E substrate temperature Tc changes with the air convection conditions around the STK672-210-E when a heat sink without fins is used.







STK672-210-E Allowable Avalanche Energy Value

### [Allowable Range in Avalanche Mode]

When driving a 2-phase stepping motor with constant current chopping using an STK672-2\*\* Series hybrid IC, the waveforms shown in Figure 1 below result for the output current,  $I_D$ , and voltage,  $V_{DS}$ .

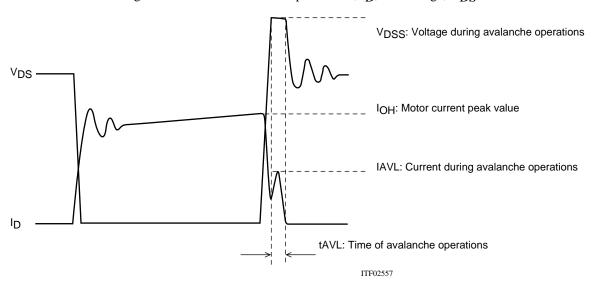


Figure 1 Output Current, I<sub>D</sub>, and Voltage, V<sub>DS</sub>, Waveforms 1 of the STK672-2\*\* Series when Driving a 2-Phase Stepping Motor with Constant Current Chopping

### STK672-210-E

When operations of the MOSFET built into STK672-2\*\* Series ICs is turned off for constant current chopping, the I<sub>D</sub> signal falls like the waveform shown in the figure above. At this time, the output voltage, V<sub>DS</sub>, suddenly rises due to electromagnetic induction generated by the motor coil.

In the case of voltage that rises suddenly, voltage is restricted by the MOSFET  $V_{DSS}$ . Voltage restriction by  $V_{DSS}$  results in a MOSFET avalanche. During avalanche operations,  $I_D$  flows and the instantaneous energy at this time, EAVL1, is represented by Equation (1).

VDSS: V units, IAVL: A units, tAVL: sec units

The coefficient 0.5 in Equation (1) is a constant required to convert the IAVL triangle wave to a square wave.

During STK672-2\*\* Series operations, the waveforms in the figure above repeat due to the constant current chopping operation. The allowable avalanche energy, EAVL, is therefore represented by Equation (2) used to find the average power loss, PAVL, during avalanche mode multiplied by the chopping frequency in Equation (1).

For V<sub>DSS</sub>, IAVL, and tAVL, be sure to actually operate the STK672-2\*\* Series and substitute values when operations are observed using an oscilloscope.

Ex. If  $V_{DSS}$ =110V, IAVL=1A, tAVL=0.2 $\mu$ s when using a STK672-210-E driver, the result is:  $PAVL=110\times1\times0.5\times0.2\times10^{-6}\times50\times10^{3}=0.55W$ 

VDSS=110V is a value actually measured using an oscilloscope.

The allowable loss range for the allowable avalanche energy value, PAVL, is shown in the graph in Figure 3. When examining the avalanche energy, be sure to actually drive a motor and observe the ID, VDSS, and tAVL waveforms during operation, and then check that the result of calculating Equation (2) falls within the allowable range for avalanche operations.

### [ID and VDSS Operating Waveforms in Non-avalanche Mode]

Although the waveforms during avalanche mode are given in Figure 1, sometimes an avalanche does not result during actual operations.

Factors causing avalanche are listed below.

- Poor coupling of the motor's phase coils (electromagnetic coupling of A phase and AB phase, B phase and BB phase).
- Increase in the lead inductance of the harness caused by the circuit pattern of the P.C. board and motor.
- Increases in V<sub>DSS</sub>, tAVL, and IAVL in Figure 1 due to an increase in the supply voltage from 24V to 36V. If the factors above are negligible, the waveforms shown in Figure 1 become waveforms without avalanche as shown in Figure 2.

Under operations shown in Figure 2, avalanche does not occur and there is no need to consider the allowable loss range of PAVL shown in Figure 3.

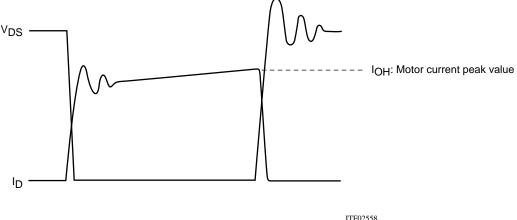
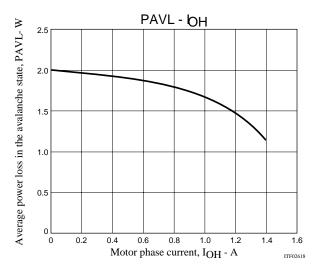


Figure 2 Output Current,  $I_D$ , and Voltage,  $V_{DS}$ , Waveforms 2 of the STK672-2\*\* Series when Driving a 2-Phase Stepping Motor with Constant Current Chopping

Figure 3 Allowable Loss Range, PAVL-I<sub>OH</sub> During STK672-210-E Avalanche Operations



#### Note:

The operating conditions given above represent a loss when driving a 2-phase stepping motor with constant current chopping.

Because it is possible to apply 2W or more at I<sub>OH</sub>=0A, be sure to avoid using the MOSFET body diode that is used to drive the motor as a zener diode.

### [Smoke Emission Precuations]

If any of the output pins 2, 3, 4, and 5 is held open, the electrical stress onto the driver due to the inductive energy accumulated in the motor could cause short-circuit followed by permanent damage to the internal MOSFET. As a result, the STK672-210-E may give rise to emit smoke.

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